

30V PNP LOW SATURATION MEDIUM POWER TRANSISTOR

Features

- BV_{CEO} > -30V
- I_C = -5.5A Continuous Collector Current
- I_{CM} = -20A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < -60mV max @ -1A
- $R_{SAT} = 24m\Omega$ @ -5.5A for Low Equivalent On-Resistance
- Exceptional Gain Linearity Down to -10mA
- hFE Specified up to -20A for High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

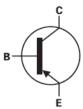
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)

Applications

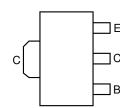
- DC-DC Converters
- MOSFET Gate Drivers
- · Charging Circuits
- Power Switches
- Motor Control







Device Schematic



Pin-Out Top View

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP2008ZTA	949	7	12	1.000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

949 = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-5.5	A
Peak Pulse Current	I _{CM}	-20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	ם	1.5 12	W mW/°C
Linear Derating Factor	(Note 6)	P_{D}	2.1 16.8	
Thermal Decistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	83	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	60	°C/W
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	3.23	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

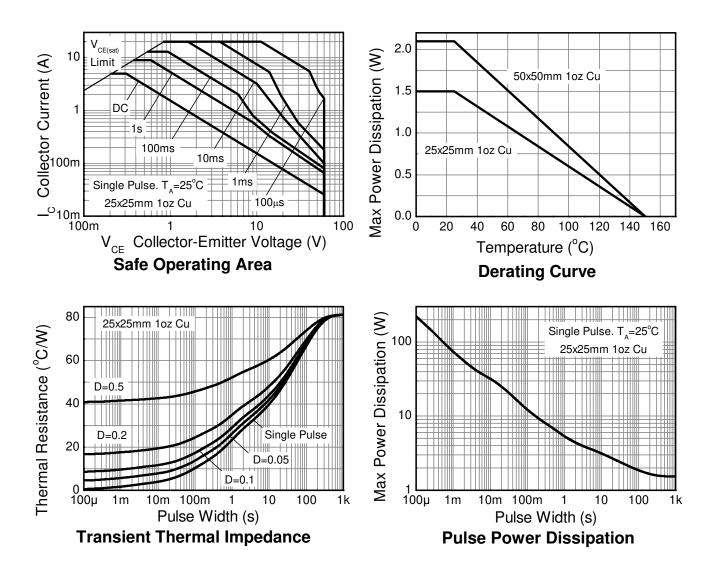
Notes:

^{5.} For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady-state.

^{6.} Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





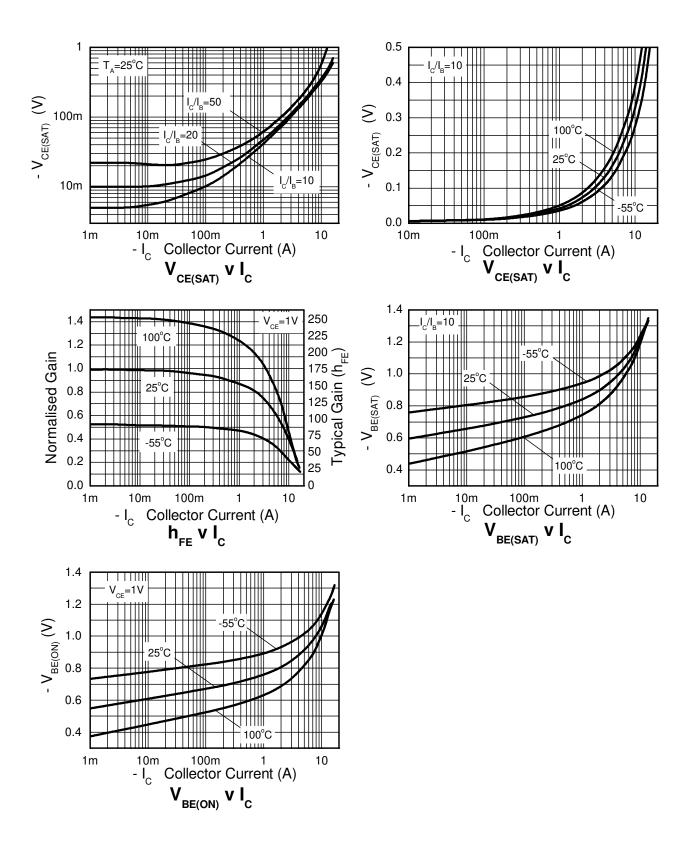
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		-50	-70	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage	BV _{CER}	-50	-70	_	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-30	-40	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8	_	V	$I_E = -100 \mu A$
Collector Cutoff Current	lono	_	< -1	-20	nA	V _{CB} = -40V
Collector Outon Ourrent	Ісво	_	_	-0.5	μΑ	$V_{CB} = -40V, T_A = +100^{\circ}C$
Collector Cutoff Current	I _{CER}	_	< -1	-20	nA	V _{CB} = -40V, R≤1kΩ
Concetor Guton Gurrent	ICER	_	_	-0.5	μΑ	V _{CB} = -40V, T _A = +100°C, R≤1kΩ
Emitter Cutoff Current	I _{EBO}		< -1	-10	nA	$V_{EB} = -6V$
			-25	-40	mV	$I_C = -0.5A$, $I_B = -20mA$
			-35	-55		$I_C = -1A$, $I_B = -100mA$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(SAT)}	_	-55	-80		$I_C = -1A$, $I_B = -20mA$
			-55	-80		$I_C = -2A$, $I_B = -200mA$
			-130	-175		$I_C = -5.5A$, $I_B = -500mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(SAT)}	_	-970	-1070	mV	$I_C = -5.5A$, $I_B = -500mA$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(ON)}	_	-860	-960	mV	$I_C = -5.5A$, $V_{CE} = -1V$
		100	225			$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Gain (Note 9)	h _{FE}	100	200	300		$I_{C} = -1A$, $V_{CE} = -1V$
Do Guiterit Gairi (Note 9)		70	145		_	$I_{C} = -5A$, $V_{CE} = -1V$
		10	20			$I_C = -20A$, $V_{CE} = -1V$
Transition Frequency	f⊤		110		MHz	$V_{CE} = -10V, I_{C} = -100mA,$
' '		_	110	_	IVII IZ	f = 50MHz
Output Capacitance (Note 9)	C _{OBO}	_	83	_	pF	$V_{CB} = -10V$, $f = 1MHz$
Switching Times	t _{ON}	_	43	_	no	$V_{CC} = -10V$, $I_{C} = -1A$,
Switching Times	t _{OFF}	_	230	_	ns	$I_{B1} = -I_{B2} = 100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

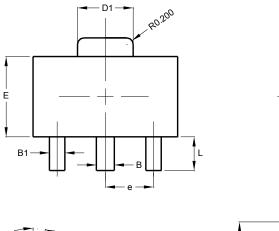


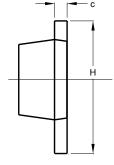


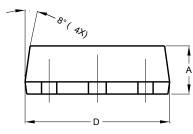
Package Outline Dimensions

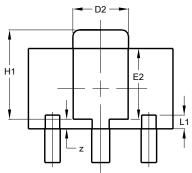
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







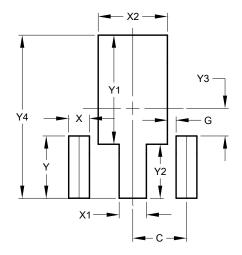


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
C	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
٦	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value
פווטופווסווום	(in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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